

Description

The 74LVT245BB is an octal transceiver designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) Pin can be used to disable the device so the buses effectively are isolated.

The device is designed for operation with a power supply range of 2.7V to 3.6V.

The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

Features

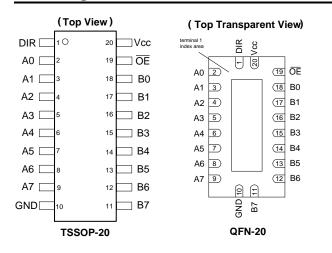
- Supply Voltage Range from 2.7V to 3.6V
- Outputs Sink 64mA or Source 32mA
- CMOS Low Power Consumption
- I_{OFF} Supports Partial Power-Down Operation
- Inputs or Outputs Accept Up to 5.5V
- Inputs Include Bus-Hold No Resistors on Unused Inputs.
- Inputs can be Driven by 3.3V or 5V Allowing for Mixed Voltage Applications
- Schmitt Trigger Action at All Inputs
- Outputs in 3-State During Power Up Allows for Hot Insertion
- Outputs Have Less than 125µA Leakage when Forced to 5.5V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 500mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments

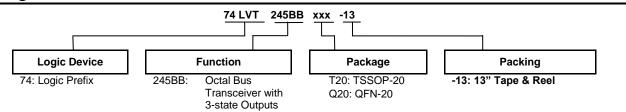


Applications

- General Purpose Logic
- Bus Driving
- Power Down Signal Isolation
- Wide Array of Products such as:
 - Servers, PCs, Notebooks, Netbooks, Ultrabooks
 - Networking Computer Peripherals, Hard Drives, CD/DVD ROM
 - TVs, DVDs, DVRs, Set Top Boxes



Ordering Information



Part Number	Package	Package	Package	13" Tape	and Reel
Fart Number	Code	(Note 4 & 5)	Size	Quantity	Part Number Suffix
74LVT245BBT20-13	T20	TSSOP-20	6.4mm x 6.5mm x 1.2mm 0.65mm lead pitch	2,500/Tape & Reel	-13
74LVT245BBQ20-13	Q20	V-QFN4525-20	2.5mm x 4.5mm x 0.95mm 0.50mm lead pitch	2,500/Tape & Reel	-13

Notes: 4. Pad layout as shown on Diodes Incorporated's package outline PDFs, which can be found on our website at

Logic Diagram

http://www.diodes.com/package-outlines.html. 5. V-QFN4525-20 is a JEDEC recognized naming convention that specifies the package thickness category as V and the number 4525 describes the package as 4.5mm × 2.5mm.

Pin Descriptions

Pin	Pin	Description
Number	Name	Description
1	DIR	Direction
2	A0	Data I/O
3	A1	Data I/O
4	A2	Data I/O
5	A3	Data I/O
6	A4	Data I/O
7	A5	Data I/O
8	A6	Data I/O
9	A7	Data I/O
10	GND	Ground
11	B7	Data I/O
12	B6	Data I/O
13	B5	Data I/O
14	B4	Data I/O
15	B3	Data I/O
16	B2	Data I/O
17	B1	Data I/O
18	B0	Data I/O
19	E	Output Enable
20	Vcc	Supply Voltage

DIR 19 OF A0 18 A1 17 <u>16</u> B2 15

В3

14 R4

13 B5

12 **B6**

<u>11</u> B7

Function Table INPUTS Operation DIR OE Data to A Bus Data to B Bus

OE	UL		
	L	L	B Data to A Bus
	L	Н	A Data to B Bus
B0	Н	Х	Bus Isolation
B1			



Absolute Maximum Ratings (Notes 6 & 7)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +4.6	V
VI	Input Voltage Range (Note 7)	-0.5 to +7.0	V
Vo	Output Voltage Range Output in OFF of HIGH State (Note 7)	-0.5 to +7.0	V
I _{IK}	Input Clamp Current VI< 0V	-50	mA
I _{OK}	Output Clamp Current V _O < 0V	-50	mA
IOL	Output Current – LOW State	128	mA
I _{OH}	Output Current – HIGH State	-64	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
Ртот	Total Power Dissipation	500	mW

Notes: 6. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

7. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

Recommended Operating Conditions (Note 8)

Symbol	Parameter	Parameter Conditions		Max	Unit
V _{CC}	Supply Voltage	_	2.7	3.6	V
VI	Input Voltage	_	0	5.5	V
Vo	Output Voltage	_	0	5.5	V
I _{OH}	High-Level Output Current	$V_{CC} = 3.0V$	—	-32	mA
		$V_{CC} = 3.0V$	—	32	~ ^
IOL	Low-Level Output Current	V _{CC} = 3.0V (Note 9)	—	64	mA
Δt/ΔV	Input Transition Rise or Fall Rate	_	—	10	ns/V
T _A	Operating Free-Air Temperature		-40	+125	°C

Notes:

8. Unused inputs should be held at V_{CC} or ground. 9. For Iol > 32mA the current duty cycle \leq 50%, Frequency > 1Khz.



Electrical Characteristics

Sumbol	Devemeter	Test Conditions	v	TA	T _A = -40°C to +85°C		
Symbol	Parameter	lest Conditions	V _{cc}	Min	Typical	Max	Unit
VIK	Input Clamping Voltage	I _{IK} = -18mA	2.7V	-1.2	-0.9	_	_
VIH	High-Level Input Voltage	—	2.7V to 3.6V	2.0	_	_	V
VIL	Low-Level input Voltage	—	2.7V to 3.6V	—	_	0.8	V
		I _{OH} = -100μA	2.7V to 3.6V	V _{CC} -0.2	V _{CC} -0.1	—	
V _{OH}	High-Level Output Voltage	I _{OH} = -8mA	2.7V	2.4	2.5	—	V
		I _{OH} = -34mA	3.0V	2.0	2.2	—	v
		I _{OL} = 100μA	2.7V to 3.6V	—	0.1	0.2	
		$I_{OL} = 24mA$	2.7V	_	0.3	0.5	
VoL	Low-Level Output Voltage	I _{OL} = 16mA	3.0V	_	0.25	0.4	V
		$I_{OL} = 24mA$	3.0V	—	0.3	0.5	
		$I_{OL} = 64 \text{mA}$	3.0V	_	0.4	0.55	
IOFF	Power Down Leakage Current	V_1 or $V_0 = 0$ to 4.5V	0V	_	±1	±100	μA
I _{O-Leakage}	Output Leakage Current	V _O = 5.5V; Output HIGH	3.6V		60	125	μA
IOZPU	Power-Up I/O Leakage	$V_0 = 0.5V \text{ to } 3.0V$ $\overline{OE} = \text{Don't Care}$	0V to 1.2V	_	15	±100	μA
IOZPD	Power-Down I/O Leakage	$V_0 = 0.5V \text{ to } 3.0V$ $\overline{OE} = \text{Don't Care}$	0V to 1.2 V	_	15	±100	μA
	Input Current	V _{I =} 5.5V	0V or 3.6V	—	1	10	μA
	Control Pins	VI = VCC or GND	3.6V	—	±0.1	±1	
lı –		V _{I =} 5.5V	3.6V	—	1	20	μΑ
	Input Current I/O Data Pins	V _{I =} V _{CC}	3.6V	—	.1	1	
	1/O Data Filis	V _I = GND	3.6V	-5	-1		
I _{BHL}	Bus Hold LOW Current	V _I = 0.8V	3.0V	75	150	_	μA
I _{BHH}	Bus Hold HIGH Current	V ₁ = 2.0V	3.0V	-150	-75	—	μA
I _{BHLO}	Bus Hold LOW Overdrive Current	V _I = 3.6V	0V to 3.0V	500	_	—	μA
I _{BHHO}	Bus Hold HIGH Overdrive Current	V _I = 3.6V	0V to 3.0V	—		-500	μA
		$V_I = GND \text{ or } V_{CC}, I_O = 0$	3.6 V	—		—	
1	Supply Current	Outputs HI	GH	—	0.13	0.19	mA
lcc	Supply Culterit	Output LO	W	—	3	12	ШA
		Outputs Disa	abled	—	0.13	0.19	
Δlcc	Additional Supply Current	One Input at V_{CC} -0.6V Others at V_{CC} or Ground Io = 0A	3.0V to 3.6V	_	100	200	μA
Cı	Input Capacitance	$\begin{array}{c} \text{Control} \\ \text{Pins} \\ \text{V}_{I} = \text{GND or} \\ \text{V}_{CC} \end{array}$	0V to 3.6V	—	4	—	pF
		I/O Pins		—	10	—	



Switching Characteristics (Figure 1)

Symbol	Parameter	V _{cc}	T _A :	Unit		
Symbol	Falanelei	v cc	Min	Тур	Max	Unit
	LOW to LUCH Propagation Dolay A to P or P to A	2.7V	—	—	5.5	
t _{PLH}	LOW to HIGH Propagation Delay A_N to B_N or B_N to A_N	3.3V ± 0.3	1.2	2.4	4.8	
		2.7V	—	_	4.7	ns
t _{PHL}	HIGH to LOW Propagation Delay A_N to B_N or B_N to A_N	3.3V ± 0.3	1.2	2.4	4.4	1
		2.7V	—	—	8.9	
t _{PZH}	Z-State to HIGH Enable Time OE to A_N or OE to B_N	3.3V ± 0.3	1.3	3.3	7.7	
		2.7V	—	—	6.9	ns
t _{PZL}	Z-State to LOW Enable Time \overline{OE} to A_N or \overline{OE} to B_N	3.3V ± 0.3	1.7	3.2	6.4	
		2.7V	—	—	6.5	
t _{PHZ}	HIGH to Z-State Disable Time OE to $A_N or OE$ to B_N	3.3V ± 0.3	2.2	3.6	6.0	
		2.7V	—	—	5.5	ns
t _{PLZ}	LOW to Z-State Disable Time OE to $A_N or OE$ to B_N	3.3V ± 0.3	2.2	3.4	5.5	

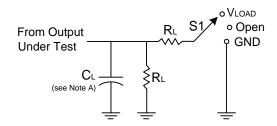
Package Characteristics

0							
Symbol	Parameter	Package	Test Conditions	Min	Тур.	Max	Unit
θ _{JA}	Thermal Resistance Junction-to-Ambient	TSSOP-20	(Note 10)	—	74	-	°C/W
θ _{JC}	Thermal Resistance Junction-to-Case	TSSOP-20	(Note 10)	—	15		°C/W
θ _{JA}	Thermal Resistance Junction-to-Ambient	V-QFN4525-20	(Note 10)	—	67	_	°C/W
θ _{JC}	Thermal Resistance Junction-to-Case	V-QFN4525-20	(Note 10)	—	20	_	°C/W

Note: 10. Test conditions for TSSOP-20 and V-QFN4525-20: Devices mounted on 4 layer FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout per JESD 51-7.

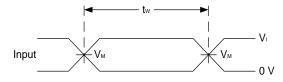


Parameter Measurement Information

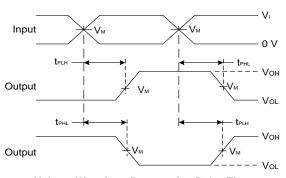


TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	VLOAD
t _{PHZ} /t _{PZH}	GND

, v	Inputs		V	N.	0	P	N/A
Vcc	VI	t _R /t _F	VM	VLOAD	CL	RL	VΔ
3.3V±0.3V	2.7V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V



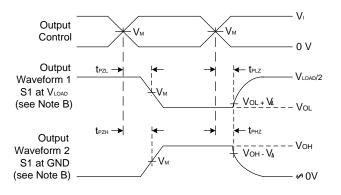
Voltage Waveform Pulse Duration





Notes: A. Includes test lead and test apparatus capacitance. B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
 C. Inputs are measured separately one transition per measurement.

Figure 1 Load Circuit and Voltage Waveforms

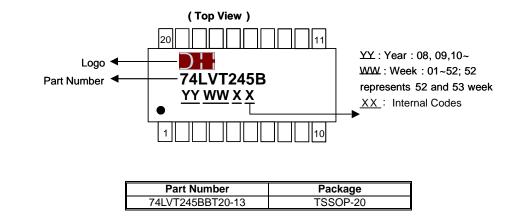


Voltage Waveform Enable and Disable Times Low and High Level Enabling

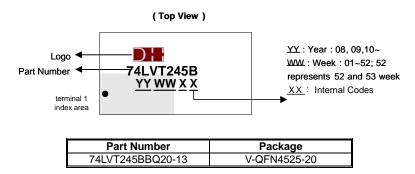


Marking Information

1) TSSOP20



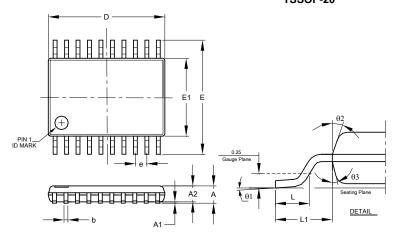
2) QFN-20 (V-QFN4525-20)





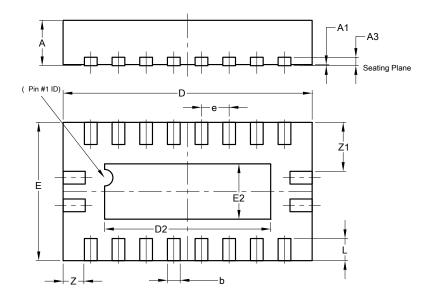
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



	TSSOP-20						
Dim	Min	Max	Тур				
Α	—	1.20	_				
A1	0.05	0.15	_				
A2	0.80	1.05	_				
b	0.19	0.30	_				
c	0.09 0.20 —						
D	6.40	6.60	6.50				
ш	6.20	6.60	6.40				
E1	4.30	4.50	4.40				
e	C	.65 BSC)				
L	0.45	0.75	0.60				
L1		1.0 REF					
θ1	0°	8°	—				
θ2	10°	14°	12°				
θ3	10°	14°	12°				
All I	Dimensi	ons in r	nm				

V-QFN4525-20

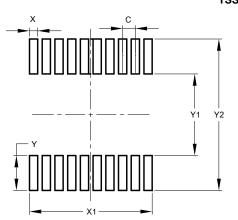


V-QFN4525-20						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	— — 0.15					
b	0.18 0.30 0.23					
D	4.45	4.55	4.50			
D2	2.85	3.15	3.00			
ш	2.45	2.55	2.50			
E2	0.85	1.15	1.00			
е	C	.50BSC)			
L	0.30	0.50	0.40			
Z	_	_	0.385			
Z1	_	_	0.885			
All	Dimensi	ons in	mm			



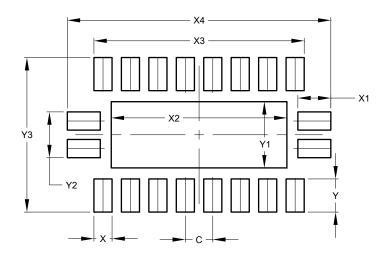
Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	6.270
Y	1.780
Y1	4.160
Y2	7.720

V-QFN4525-20



Dimensions	Value (in mm)
С	0.500
Х	0.330
X1	0.600
X2	3.200
X3	3.830
X4	4.800
Y	0.600
Y1	1.200
Y2	0.830
Y3	2.800

TSSOP-20



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 TC74VCX164245(EL,F
 MC74LCX245MNTWG
 TC74LCX16245(EL,F)
 TC7WPB8306L8X,LF(S

 MM74HC245AMTCX
 74LVX245MTC
 74ALVC16245MTDX
 74LCXR162245MTX
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 JM38510/65553BRA
 FXL2TD245L10X
 74LVC1T45GM,115
 74LVC245ADTR2G
 TC74AC245P(F)
 SNJ54LS245FK
 74LVT245BBT20-13

 74AHC7245D.112
 SN74LVCH16952ADGGR
 CY74FCT16245TPVCT
 SN74ABT16646DGGR
 SN75138NSR
 AP54RHC506BLT-R

 74HC7643N
 MC100EP16DTR2G
 5962-9221403MRA
 74FCT16245ATPAG
 74FCT16245ATPVG
 74FCT16245ETPAG

 74FCT163245CPVG
 74FCT245CTSOG
 74HC646N
 74AVC8T245PW,118
 TC7QPB9306FT(EL)
 SY88808LMH